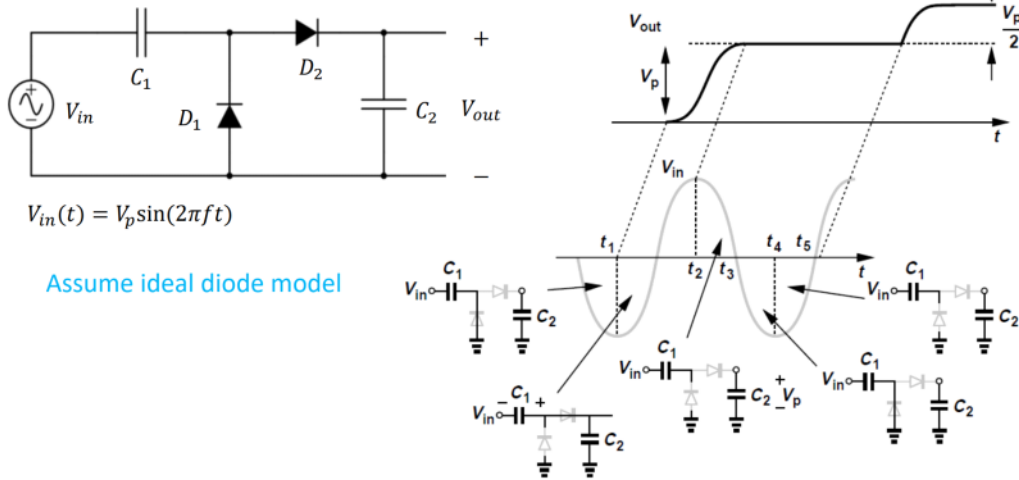
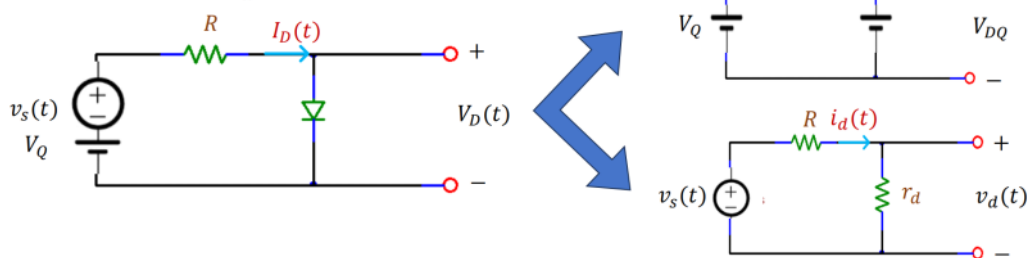


## Actual voltage doubler circuits



## Procedure

- DC analysis to get  $I_{DQ}$ .
- Calculate the diode small-signal resistance  $r_d = \frac{V_T}{I_{DQ}} \big|_{V_{DQ}}$ .
- $v_d(t) = \frac{v_s(t)r_d}{r_d + R}$



## Small-signal model approximation error

$$I_D(t) = I_s e^{[V_{DQ} + v_d(t)]/nV_T} = I_s e^{V_{DQ}/nV_T} e^{v_d(t)/nV_T} = I_{DQ} e^{v_d(t)/nV_T}$$

$$I_D(t) = I_{DQ} + i_d(t)$$

$$\rightarrow i_d(t) = I_D(t) - I_{DQ} = I_{DQ}(e^{v_d(t)/nV_T} - 1) \quad \text{actual } i_d(t)$$

$$\text{Small-signal approximated } i_d(t): \hat{i}_d(t) = I_{DQ} v_d(t)/nV_T$$

$$\rightarrow \frac{i_d(t)}{\hat{i}_d(t)} = \frac{e^{v_d(t)/nV_T} - 1}{v_d(t)/nV_T}$$

$v_d(t)/nV_T$	0.1	0.2	0.3	0.4	0.5	0.6	0.7
$\frac{i_d(t)}{\hat{i}_d(t)}$	1.05	1.11	1.17	1.23	1.30	1.37	1.45

Kursusl sning:

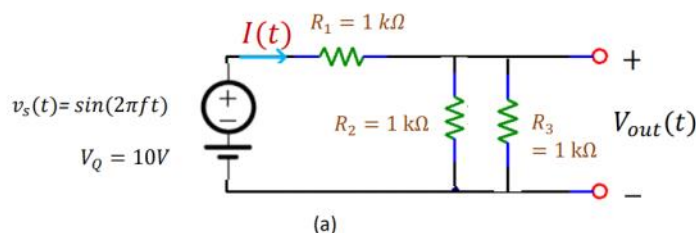
Assignments:

3.1:

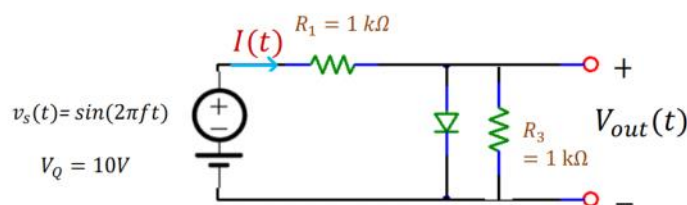
Assume the diode has a voltage drop of 0.7 V when only DC voltage  $V_Q$  is applied. For the circuits in Fig. 1 (a) and (b),

- What is the expression of  $V_{out}(t)$ ?
- The input voltage change is  $1/10 = 10\%$ , what is the output change?

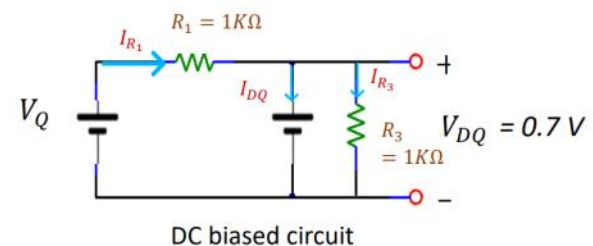
Hint: For Fig. 1(b), use the small-signal model.



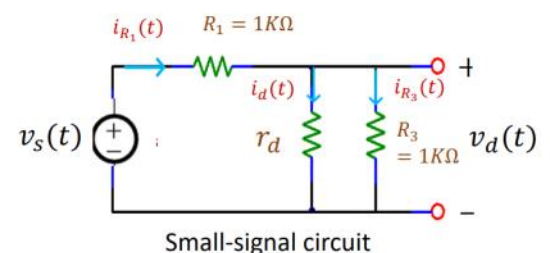
(a)



(b)



DC biased circuit



Small-signal circuit

(c)

Fig. 1

**Solution:**

For Fig. 1 (a):

$$R_{23} = R_2 || R_3 = 0.5 \text{ K}\Omega \quad \text{--- } R_2 \text{ and } R_3 \text{ are in parallel}$$

- $V_{out}(t) = \frac{R_{23}}{R_1 + R_{23}} V(t) = \frac{1}{3} [10 + \sin(2\pi ft)]$
- When input changes 10%, i.e.,  $V(t)$  changes from  $V(t_1) = 10 \text{ V}$  to  $V(t_2) = 11 \text{ V}$ ,  
 $\rightarrow V_{out}(t)$  changes from  $V_{out}(t_1) = \frac{10}{3} \text{ V}$  to  $V_{out}(t_2) = \frac{11}{3} \text{ V}$   
 $\rightarrow \frac{V_{out}(t_2) - V_{out}(t_1)}{V_{out}(t_1)} = 10\%$ , i.e., the output also changes 10%.

For Fig. 1 (b):

**Solution:**

(c)

Fig. 1

For Fig. 1 (a):

$R_{23} = R_2 || R_3 = 0.5 \text{ K}\Omega$  ---  $R_2$  and  $R_3$  are in parallel

- $V_{out}(t) = \frac{R_{23}}{R_1 + R_{23}} V(t) = \frac{1}{3} [10 + \sin(2\pi ft)]$
- When input changes 10%, i.e.,  $V(t)$  changes from  $V(t_1) = 10 \text{ V}$  to  $V(t_2) = 11 \text{ V}$ ,
  - $V_{out}(t)$  changes from  $V_{out}(t_1) = \frac{10}{3} \text{ V}$  to  $V_{out}(t_2) = \frac{11}{3} \text{ V}$
  - $\frac{V_{out}(t_2) - V_{out}(t_1)}{V_{out}(t_1)} = 10\%$ , i.e., the output also changes 10%.

For Fig. 1 (b):

Decompose the circuit into the DC biased circuit (top) and small-signal circuit (bottom) as in Fig.1 (c).

Do DC analysis to obtain  $I_{DQ}$  and  $r_d$  according to the DC biased circuit.

$$\text{KVL: } V_Q = I_{R_1} R_1 + V_{DQ} \Rightarrow I_{R_1} = \frac{V_Q - V_{DQ}}{R_1} = \frac{10 - 0.7}{1000} = 9.3 \text{ mA}$$

$$\text{The voltage drop across } R_3 \text{ is equal to } V_{DQ} = 0.7 \text{ V} \Rightarrow I_{R_3} = \frac{V_{DQ}}{R_3} = \frac{0.7}{1000} = 0.7 \text{ mA}$$

$$\text{KCL: } I_{R_1} = I_{DQ} + I_{R_3} \Rightarrow I_{DQ} = I_{R_1} - I_{R_3} = 8.6 \text{ mA}$$

$$\Rightarrow r_d = \frac{V_T}{I_{DQ}} = \frac{26 \text{ mV}}{8.6 \text{ mA}} = 3.0 \Omega$$

According to the small-signal circuit:

$R_{d,3} = r_d || R_3 \approx 3 \Omega$  ---  $r_d$  and  $R_3$  are in parallel

$$\Rightarrow v_d(t) = \frac{R_{d,3}}{R_{d,3} + R_1} v_s(t) = \frac{3}{1003} v_s(t)$$

- $V_{out}(t) = V_{DQ} + v_d(t) = 0.7 + \frac{3}{1003} v_s(t)$
- When input changes 10%, i.e.,  $V(t)$  changes from  $V(t_1) = 10 \text{ V}$  to  $V(t_2) = 11 \text{ V}$  ( $v_d(t_2) = 1 \text{ V}$ )
  - $V_{out}(t)$  changes from  $V_{out}(t_1) = 0.7 \text{ V}$  to  $V_{out}(t_2) = (0.7 + \frac{3}{1003}) \text{ V}$
  - $\frac{V_{out}(t_2) - V_{out}(t_1)}{V_{out}(t_1)} = 0.43\%$ , i.e., the output also changes only 0.43%. The output voltage is insensitive to the input voltage changes.